CONTRASTING PATHWAYS TO MOTT GAP COLLAPSE IN ELECTRON AND HOLE DOPED CUPRATES

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Recent ARPES measurements on the electron-doped cuprate Nd_{2 x} Ce_xCuO₄ can be interpreted in a mean eld model of uniform doping of an antiferrom agnet, with the M ott gap closing near optim aldoping. M ode coupling calculations con m the m ean eld results, while clarifying the relation between the M ott gap and short-range magnetic order. The same calculations nd that hole doped cuprates should follow a strikingly di erent doping dependence, involving instability toward spiral phases or stripes. N evertheless, the magnetic order (now associated with stripes) again collapses near optim al doping.

1. Introduction

1.1. M ode Coupling Theories

In conventional itinerant ferro- and antiferrom agnets, mode-coupling theories^{1;2} have proven of value in treating the role of uctuations in reducing or elim inating long-range order, as well as in the developm ent of local moments, Curie-like susceptibility, and in general the crossover to magnetic insulators. Sim ilar approaches have been applied to charge-density wave system s^3 and the glass transition⁴.

A tem pts to apply such a form alism to study the antiferrom agnetism of the cuprate superconducting com pounds have been flustrated, since the antiferrom agnetic (AF) phase is found to be unstable against hole doping, toward either an incom mensurate AF phase⁵ or phase separation⁶. Here, it is demonstrated that this tendency to instability is either absent or greatly reduced in electron-doped cuprates, and the mode coupling analysis can provide a detailed description of the collapse of the M ott gap with doping. The results are of great interest of them selves: the collapse is associated with one or more quantum critical points (Q CPs), and superconductivity is optimized close to one Q CP. However, the results have an additional importance in the light they shed on the more complicated problem of the hole doped cuprates. First, the e ective Hubbard U parameter has a signi cant doping dependence, from U W at half lling (where W = 8t is the bandwidth and t the nearest neighbor hopping parameter) to U W =2 near optim aldoping. Secondly, the sam e mode coupling theory which works so well for electron-doped cuprates, breaks down for hole doping, due to the above noted electronic instability. This suggests that (a) the electronhole asym metry must be due to a band structure e ect and (b) a suitable generalization of mode coupling theory should be able to incorporate the e ects of this instability.

1.2. ARPES of N d₂ $_{x}Ce_{x}CuO_{4}$

Recently, A m itage, et al.⁷ succeeded in m easuring angle-resolved photoem ission spectra (ARPES) of Nd_{2 x} Ce_xCuO₄ (NCCO) as a function of electron doping, from essentially the undoped insulator x = 0 to optim aldoping x = 0.15. The doping dependence is strikingly di erent from that found in hole-doped La_{2 x} Sr_xCuO₄ (LSCO)^{8;9}. Both systems start from a M ott insulator at half lling, with ARPES being sensitive only to the lower Hubbard band (LHB), approximately 1eV below the Ferm i level E_F . W ith hole doping, the LHB remains well below E_F while holes are added in mid-gap states (as expected, e.g., in the presence of nanoscale phase separation¹⁰); for electron doping, the Ferm i level shifts to the upper Hubbard band (UHB), and the electrons appear to uniform ly dope the antiferrom agnet.

Remarkably, the full doping dependence can be simply described by a mean-eld (MF)t t⁰ U Hubbard model¹¹, where t⁰ is the second neighbor hopping, U is the onsite coulomb repulsion, and a one band (copper only) model was assumed for simplicity.^a A key noting is that the Hubbard U is doping dependent, leading to a quantum critical point (QCP) just beyond optim al doping, where the Mott gap vanishes. The appearance of a peak in superconductivity near an AFM QCP is a fairly common occurance¹²; in particular, something similar has been observed¹³ in the hole-doped cuprates. However, the MF theory is problem atic, in that the Mott gap is associated with long-range Neel order, and the MF model predicts anom alously high values for T_N .

^aA ctually, in Ref.¹¹ a third neighbor hopping t^{0} was included to optim ize the t to the experim ental Ferm isurface curvature. The changes induced by this parameter are small, and it will be ignored in the present calculations.

2. M ode Coupling Theory

This anom abus behavior can be cured by incorporating the role of uctuations. Indeed, it is known that in a two-dimensional system, the Neel transition can only occur at T = 0 { the M erm in-W agner (M W) theorem ¹⁴. By treating uctuations within a mode coupling analysis, the M W theorem is satis ed¹⁵, and the M ott gap is completely decoupled from long-range spin-density wave (SDW) order. Even though $T_N = 0$ a large M ott (pseudo)gap is present even well above room temperature near half lling { due to short-range AFM order. The M F gap and transition temperature are found to be approximately the pseudogap and T the onset temperature for the pseudogap opening.

The calculation can be sum marized as follows. In a path integral formulation of the Hubbard model¹⁶, the quartic term is decoupled via a Hubbard-Stratonovich transform ation and the ferm oinic degrees integrated out. The resulting action is then expanded to quartic order in the Hubbard-Stratonovich elds . The quadratic interaction reproduces the RPA theory of the Hubbard model { the quadratic coe cient is just U $_{0q}$, where $_{0q}$ is the (inverse) Stoner factor $_{q} = 1$ U $_{0}$ ($\mathcal{Q} + q; !$) (here $\mathcal{Q} = (;)$ is the wave vector associated with the commensurate SDW). The quartic interaction, parametrized by the coe cient u evaluated at \mathcal{Q} , ! = 0, represents coupling between di erent magnetic modes. The elects of this term cannot be treated in perturbation theory, and a self-consistent renorm alization (SCR) schem e^2 is introduced to calculate the renorm alized Stoner factor $_{q} = _{0q} +$. A self-consistent equation for is found, which can be solved if the band parameters and the interactions U and u are known.

To simplify the calculation, is assumed to be independent of q and !, and the Stoner factor is expanded near Q as

$$_{q}(!) = + Aq^{2} B!^{2} iC!;$$
 (1)

similar to the form assumed in nearly antiferrom agnetic Ferm i liquid $(N\,A\,F\,L)^{17}$ theory. The imaginary term linear in frequency is due to the presence of low energy magnon excitations in the vicinity of the hot spots' { the points where the Ferm i surface intersects the B rillouin zone diagonal. Here uctuations tow and long-range N eel order lead to strong, B ragg-like scattering which ultimately leads to the magnetic B rillouin zone boundary at T_N . Independent of the parameter values, it is found that > 0 for T > 0 { the MW theorem is satisticed, while for electron doping ! 0 as T ! 0 up to a critical doping { there is a QCP associated with T = 0 SDW order. For hole doping the calculation breaks down { the parameter A is negative in a signi cant doping regime, as will be discussed further below.

The key insights of mode coupling theory are:

The M ott transition is dom inated by hot spot physics, which creates zone-edge m agnons. The condensation of these m agnons creates a new zone boundary, and opens up a gap (the M ott gap) in the electronic spectrum . In two dimensions (2D), there can be no Bose condensation at nite tem – peratures, but the pileup of lowest energy m agnons as T decreases leads to the appearence of a M ott pseudogap and a T = 0 transition to long-range SDW order.

Evidence for the existence of local m agnons comes from well-de ned plateaus in the spin susceptibility. Plateaus are seen in (a) the doping dependence of the susceptibility at Q, (b) the q dependence of the susceptibility near Q, and (c) the ! dependence of the susceptibility (both real and im aginary parts) at Q. These plateaus introduce cuto s in the q and ! dependence of the Stoner factor, Eq. 1, which in general cannot be sent to 1, in contrast to the NAFL m odel. Also, the atness of the plateau tops m akes it di cult to estimate the m odel parameters from rst principles. In particular A is strongly tem perature dependent, while u is anom alously sm all (this problem had been noted previously¹⁸).

A nite N eel tem perature can be generated by interlayer coupling. In the cuprates, such coupling is typically flustrated, and N eel order m ore likely arises from a K osterlitz-T houless transition, after the spin dimensionality is reduced by, e.g., spin-orbit coupling¹⁹.

3. Results

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3.1. Susceptibility

In analyzing the ARPES data, a tight-binding band is assumed,

$$_{k} = 2t(c_{x} + c_{y}) \quad 4t^{0}c_{x}c_{y};$$
 (2)

with $c_i = \cos k_i a$, t = 0.326eV, and $t^0 = t = 0.276$. The Hubbard U is doping dependent, U = t = 6, 5, 3.5, and 2.9 at x = 0, -0.04, -0.10, and -0.15, respectively, and the mode coupling constant is adjusted to reproduce the low-temperature spin sti ness at half lling²⁰, u¹ = 0.256 eV. The bare susceptibility

$$_{0}(q;!) = \frac{X + f(x) + f(x+q)}{x + x + q + 1 + 1};$$
(3)

is evaluated near Q to determ ine the parameters of Eq.1.

The susceptibility $_0$ (\mathcal{Q} ;0) has approximately the shape of a plateau as a function of doping, Figure 1a, bounded by the critical points x_H and x_C

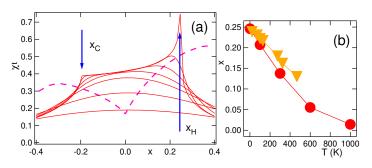


Figure 1. (a) Susceptibility $_0$ at Q as a function of doping for several tem peratures. From highest to low est curves near x = 0:1, the tem peratures are T = 1, 100, 300, 600, 1000, 2000, and 4000 K.D ashed line = $1=U_{eff}$. (b) C incluss = pseudo-VHS (peak of $_0$) as a function of tem perature T_V ; triangles = $T_{in \, com \, m}$.

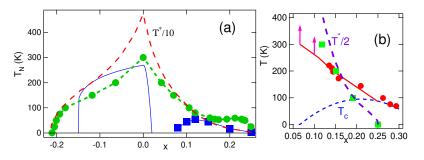


Figure 2. (a) M ean-eld transition temperature T (long dashed line) compared with N eeltem perature of N C C O and LSC O (solid line) plus m agnetic transition temperature of stripe ordered phase in N d-substituted LSC O ²⁵, C ircles = m odel calculation of T_N assuming unfrustrated interlayer hopping. (b) C om parison of m ean-eld transition (long dashed line) to various estimates of pseudogap temperature: from photoem ission²² (solid line), heat capacity²³ (squares) and tunneling²⁴ (circles = =3, with the tunneling gap). Short dashed line = superconducting T_c .

where the Ferm i surface ceases to have hot spots. These special points act as natural phase boundaries for antiferrom agnetism , due to the sharp fallo

in o of the plateau.

The special point $x_{\rm H}$ coincides at T=0 with the Van H ove singularity (VHS) of the band. Rem arkably, the susceptibility peak has a strong tem – perature dependence^{21}, de ning a pseudo-VHS; Fig. 1b shows the tem perature $T_{\rm V}$ (x), at which the susceptibility peaks at x. This can be understood by noting that the energy denom inator of , Eq.3, is independent of t^0 , and thus would lead to a large peak at half lling, x=0 (associated with states along the zone diagonal). At low tem peratures, the di erence in Ferm i functions in the num erator cuts this o , and forces the peak to coincide

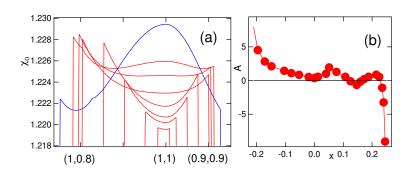


Figure 3. (a) Expanded view of susceptibility $_0$ on the plateaus near Q for a variety of dopings at T = 1K. From highest to low est curves near Q, the chem ical potentials are = -0.25, -0.22, -0.21, -0.20 (x= 0), -0.15, -0.10, -0.05, and -0.02eV. All curves except = 0.20eV have been shifted vertically to twithin the expanded fram e. (b) C alculated A (x).

with the VHS.AsT increases, more states near the zone diagonals become available, causing the peak susceptibility to shift towards half lling. For a tem perature $T_{\rm in\,com\,m}$ slightly above $T_{\rm V}$, the curvature A becomes negative, signalling the instability of the commensurate AFM state.

The dashed line in Fig. 1a represents $1=U_{eff}$, where U_{eff} is a doping dependent H ubbard U, estim ated from a screening calculation¹¹. The intersection of the dashed line with one of the solid lines de nest the mean-eld N eel transition, $_0U_{eff} = 1$, Fig. 2a (long-dashed line). As will be shown below, once uctuations are included, the mean-eld transition turns into a pseudogap onset T, while the actual onset of long range m agnetic order is suppressed to much lower temperatures. From Fig. 2b, it can be seen that the mean-eld T is consistent with a number of estim ates^{22;23;24} of the experimental pseudogap for hole doping, while a simple calculation of the three-dimensional N eel transition associated with interlayer coupling (circles in Fig.2a { see the Appendix for details) can approximately reproduce the experimental observations (solid lines) { if the transitions associated with m agnetic order on quasistatic stripes²⁵ are included (squares).

In addition to plateaus in doping, the hot spots lead to plateaus in the frequency and wave number dependence of $_0$ (g;!). For instance, Fig. 3a shows plateaus in $_0$ (Q + g;0) at a series of dopings at T = 1K. Once $_0$ is known the parameters A and C of Eq. 1 can be calculated; B is quite sm all, and can in general be neglected. The plateau width q_c ! O as x ! x_c , leading to a strong T-dependence of A, Fig. 3b.

G iven the model parameters, the self-consistent equation for becomes 15

$$= _{0} + \frac{3ua^{2}}{^{2}C} \int_{0}^{Z} dq^{2} dq^{2} dx \operatorname{coth} \frac{x}{2CT} \frac{x}{(+Aq^{2})^{2} + x^{2}} : \qquad (4)$$

which has the approxim ate solution

$$Z \qquad _{0} = \frac{3ua^{2}T}{A}\ln\left(\frac{2CT}{e}\right); \qquad (5)$$

where $_{0} = _{0} + 1$,

$$= 1 + \frac{3uq_c^2 a^2}{^2C} \frac{1}{2} \ln [1 + a_q^2] + \frac{\tan^{-1}(a_q)}{a_q} ; \qquad (6)$$

 $a_q = Aq_c^2 = 1$, and q_c and q_c are wavenumber and (normalized) frequency cuto s, respectively, and the exact form of Z is not required. From the logarithm in Eq.5, must be greater than zero for all T > 0, so there is no nite temperature phase transition. At low temperatures, the on the left hand side of Eq.5 can be neglected, leading to a correlation length

$$^{2} = \frac{A}{2} = {}^{2}_{0} e^{4} {}^{s=T};$$
 (7)

with ${}^2_0 = eA = 2TC$ and

$$_{s} = \frac{A j_{0} j}{24 u a^{2}}$$
(8)

Here, $_0$ is the quantum corrected Stoner factor, which controls the T = 0 QCP: there is long-range N eelorder at T = 0 whenever $_0$ 0, or U $_0$.

3.2. ARPES Data

From the susceptibility, the contribution to the electronic self energy due to one magnon scattering can be calculated. The imaginary part of the susceptibility can be written

Im
$$(\tilde{K};!) = \frac{q^2_{0} X^{2_{|}=C}}{V_{q}^{|}=C} d [n() + f(_{\tilde{K}+q})]$$

 $(! + _{R+q}) \frac{C}{(+Aq^{2})^{2} + (C)^{2}}:$ (9)

where the coupling is approximately g^2_0 , 3U=2. Since is peaked near zero when q' Q, Im is approximately a -function at $_{R+Q}$. Approximating Im = 2^2 (! $_{R+Q}$), then

$$^{2} = \frac{U}{8u} (_{0}):$$
 (10)

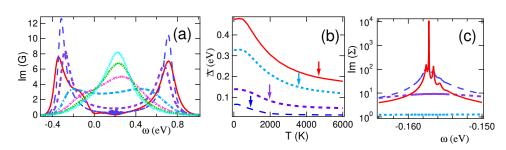


Figure 4. (a)Spectral function for x = 0.0, $\tilde{k} = (=2; =2)$, at T = 100, 500, 1000, 2000, 3000, 4000, and 5000K (larger splittings corresponding to lower T's). (b) (T); solid line: x = 0.0, dotted lines: x = 0.04, short-dashed lines: x = 0.10, long-dashed lines: x = 0.15. (c)Im () for x = 0, $\tilde{k} = (;0)$ at T = 100 (solid line), 500 (long dashed line), 1000 (short dashed line), and 2000K (dotted line).

The importance of this result can be seen by noting that, by K ram ers-K ronig,

$$\operatorname{Re}(\tilde{K};!) = \frac{2}{!}; \qquad (11)$$

so that

$$G^{1}(\vec{k};!) = ! \qquad R \in \mathbb{R}(\vec{k};!) = \frac{(! R)(! R + q)^{2}}{! R + q}: (12)$$

The zeroes of G¹ are identical to the mean eld results for long-range AFM order^{26;11}, except that the long-range gap = U < m_z > is replaced by the short-range gap $U^{1} < m_{z}^{2} > .$

Figure 4a shows the spectral function A $(\tilde{k};!) = \text{Im } (G(\tilde{k};!)) = \text{ for } x = 0 \text{ at } \tilde{k} = (=2; =2) \text{ at a series of tem peratures. The spectrum is split into upper and low er H ubbard bands, with a gap approxim ately 2. The short-range order gap is plotted in Fig. 4b; it is nite for all tem peratures, but increases signi cantly close to the mean-eld Neel tem perature (arrow s). The net dispersion for two dopings, <math>x = 0, -0.15$, is shown in Fig. 5; it is in good agreement with the experimental⁷ and mean-eld¹¹ results. The build up ofhot spotm agnons is rejected in the grow th of Im (($\tilde{k};!$)) near $! = \frac{k+\alpha}{k+\alpha}$, Fig. 4c (note the logarithm is scale).

4. Im plications for H ole D oping

O ne expects, and observes, a certain degree of sym m etry between electron and hole doping: there is a susceptibility plateau associated with hot spots, Fig. 1, which term inates near optim aldoping; the term ination of m agnetic order in electron-doped cuprates at a QCP near optim aldoping is m atched

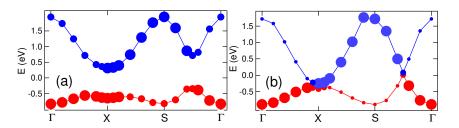


Figure 5. D ispersion relations for (a) x = 0 and (b) x = -0.15, at T = 100K. B rillouin zone directions are = (0;0), X = (;0), S = (;).

in hole-doped cuprates by the observation of a QCP near optimal doping which appears to be associated with loss of magnetic correlations¹³; and in both cases an optimal, probably d-wave superconductivity is found near the QCP. Also, it is expected that U would have a similar decrease with doping for either electron or hole doping (see the model calculation, dashed line in Fig. 1).

On the other hand, there are also signi cant di erences, not the least of which is the magnitude of the superconducting T_c . Most signi cantly, there is considerable evidence for the appearence of nanoscale phase separation { either in the form of stripes²⁷ or blobs²⁸ { for hole doped cuprates, while the evidence is weaker or absent for electron doping^{29;30}. As noted above, this di erence arises naturally within the present calculations, which ind instability of the commensurate magnetic order for hole doping only (e.g., Fig. 3).

G iven these similarities and di erences, the present calculations can shed some light on aspects of hole-doped physics:

(1) A large pseudogap is present at half lling, associated with short-rangem agnetic order. Just as for electron doping, it should persist with hole doping until short-rangem agnetic order is lost. The observed¹³ connection of the loss ofm agnetic uctuations with the collapse of the pseudogap near x = 0.19 strongly suggests an identi cation of the observed pseudogap at T with the M ott pseudogap, as found for electron doping. W hile a num ber of theories have proposed that the pseudogap is associated with superconducting uctuations, these seem to turn on at a temperature lower than T .³¹. R em arkably, despite the com plications associated with stripes, the m ean-eld transition temperature is within a factor of two of the observed pseudogap temperatures, F ig. 2b.

(2) The present calculations point to a close connection between the Van Hove singularity (VHS) and the instability of commensurate magnetic order, Fig. 1b. This strongly suggests that the VHS is responsible for the

asymmetry between electron and hole doping, and in particular for any frustrated phase separation.

(3) If the stripes are associated with frustrated phase separation, it is in portant to identify the second (m etallic) phase and understand what interaction stabilizes it (particularly since this is likely to be the phase in which high- T_c superconductivity arises). In a purely Hubbard model, this would be a ferrom agnetic phase, hence probably incompatible with superconductivity. However, the reduction of U with doping found here strengthens the case for a nonm agnetic charge stripe associated with interactions beyond the Hubbard model².

5. D iscussion: Polaron Lim it

In the very low doping limit, isolated charge carriers should form (spin or charge) polaronic states for either sign of doping. The asymmetry between hole and electron doping would then be rejected in interpolaronic interactions being strongly attractive for hole doping. For electron doping, the isolated polarons could be much more easily pinned in the AFM background, leading to the much stronger localization found in NCCO³³.

A cknow ledgm ents

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Appendix: c-A x is C oupling

A toy model is introduced to study the e ect of interlayer coupling on generating a nite N eel transition temperature $T_{\rm N}$. The interlayer hopping is assumed to be a constant t_z independent of in-plane momentum. W hile a term of the form $t_z \ (c_x \ c_y)^2$ would not greatly change the results, in the physical cuprates alternate CuO₂ planes tend to be staggered, which should lead to frustration $t_z \ ({\tt Q}\)=0$, and greatly reduced interlayer coupling is negligible, and that the N eel transition is actually of K osterlitz-T houless form , due to reduced spin dimensionality caused by spin-orbit coupling¹⁹.

N evertheless, it is instructive to see how constant-tz interlayer coupling

can generate a $\mbox{ nite } T_N$. The revised Eq.5 can be written in the symbolic form

$$Z = _{0} + \frac{T}{T_{0}} ln \left(\frac{D_{0}}{D + 2} \right);$$
 (A.1)

where $T_0=~^2A=6ua^2$ and $D_0=4C\ T=e$ are (doping-dependent) constants (Eq. 5 { the extra =2 in T_0 coming from the q_z -integral) and 34 D / t_z^2 . Thus for nite t_z , there is a non-zero T_N given by the solution of $_0+T=T_0=0,w$ ith $T_0=T_0=\ln(D_0=D)$. For the calculation in Fig.2a, a constant $T_0=1200K$ was assumed, but it is interesting to note that when the correct doping dependence of the parameters is included, T_N ! 0 as A ! 0, suggesting that the much steeper fallo of T_N with hole doping is related to phase separation.

Equation A .1 can be rewritten using Eq. 8. The N eel transition occurs when

$$J_{z}[(T_{N}) = {}_{0}(T_{N})]^{2} = T_{N};$$
 (A.2)

with $J_z=J = (t_z=t)^2$, = 16C =edU, d = D = t_z^2 and J = 4 t^2 =U, suggestive of a form of interlayer coupling proposed earlier³⁵.

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